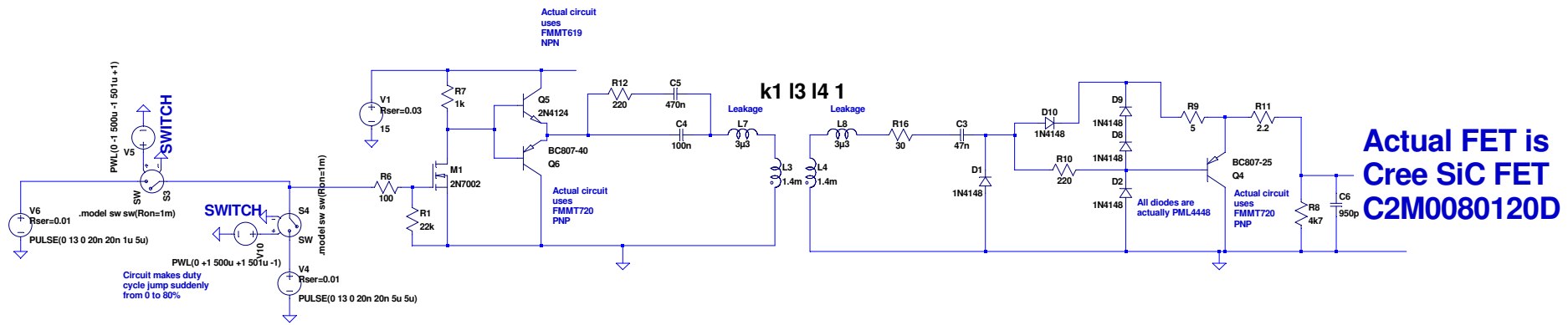


Both these gate drive txfmr circuits have the same series resistance, but circuit A is better...it suffers much less amplitude of ringing at the FET gate, and manages to always switch the FET gate to zero volts when OFF, whereas circuit B, for a time (at 480us), does not manage to switch the FET gate OFF to zero volts

A



B

